# TLC7528C, TLC7528E, TLC7528I DUAL 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTERS

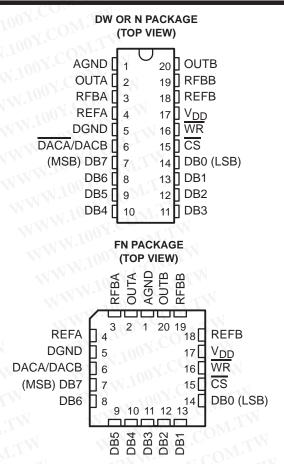
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- Easily Interfaced to Microprocessors
- On-Chip Data Latches
- Monotonic Over the Entire A/D Conversion Range
- Interchangeable With Analog Devices AD7528 and PMI PM-7528
- Fast Control Signaling for Digital Signal Processor (DSP) Applications Including Interface With TMS320
- Voltage-Mode Operation
- CMOS Technology

KEY PERFORMANCE SPECIFIC	KEY PERFORMANCE SPECIFICATIONS					
Resolution	8 bits					
Linearity Error	1/2 LSB					
Power Dissipation at V <sub>DD</sub> = 5 V	20 mW					
Settling Time at VDD = 5 V	100 ns					
Propagation Delay Time at V <sub>DD</sub> = 5 V	80 ns					

# description

The TLC7528C, TLC7528E, and TLC7528I are dual, 8-bit, digital-to-analog converters designed with separate on-chip data latches and feature exceptionally close DAC-to-DAC matching. Data is transferred to either of the two DAC data latches through a common, 8-bit, input port. Control input DACA/DACB determines which DAC is to be loaded. The load cycle of these devices is similar



to the write cycle of a random-access memory, allowing easy interface to most popular microprocessor buses and output ports. Segmenting the high-order bits minimizes glitches during changes in the most significant bits, where glitch impulse is typically the strongest.

These devices operate from a 5-V to 15-V power supply and dissipates less than 15 mW (typical). The 2- or 4-quadrant multiplying makes these devices a sound choice for many microprocessor-controlled gain-setting and signal-control applications. It can be operated in voltage mode, which produces a voltage output rather than a current output. Refer to the typical application information in this data sheet.

The TLC7528C is characterized for operation from 0°C to 70°C. The TLC7528I is characterized for operation from –25°C to 85°C. The TLC7528E is characterized for operation from –40°C to 85°C.

#### **AVAILABLE OPTIONS**

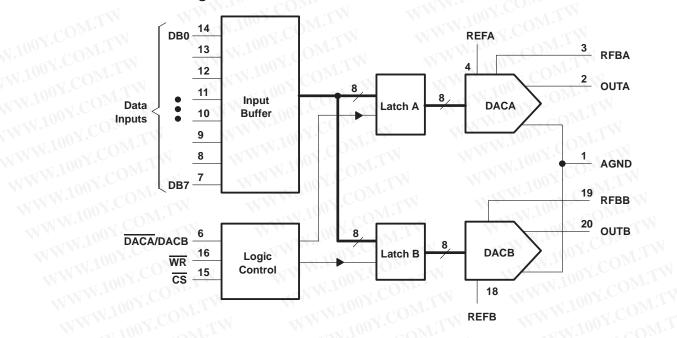
COn.	W Wr.	PACKAGE	WT
100 TA CO	SMALL OUTLINE (DW)	CHIP CARRIER (FN)	PLASTIC DIP (N)
0°C to 70°C	TLC7528CDW	TLC7528CFN	TLC7528CN
−25°C to 85°C	TLC7528IDW	TLC7528IFN	TLC7528IN
-40°C to 85°C	TLC7528EDW	TLC7528EFN	TLC7528EN



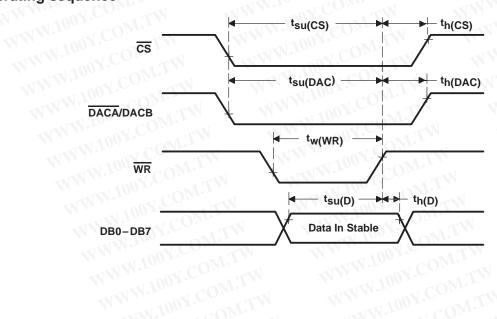
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## functional block diagram



# operating sequence



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# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V <sub>DD</sub> (to AGND or D	GND)	v.1042	-0.3 V to 16.5 V
Voltage between AGND and DGND			±V <sub>DD</sub>
Input voltage range, V <sub>I</sub> (to DGND)			
Reference voltage, V <sub>refA</sub> or V <sub>refB</sub> (to AGNI	D)		±25 V
Feedback voltage V <sub>RFBA</sub> or V <sub>RFBB</sub> (to AG			
Input voltage (voltage mode out A, out B to			
Output voltage, VOA or VOB (to AGND)			
Peak input current			10 μΑ
Operating free-air temperature range, T <sub>A</sub> :			
ON TWO THE THE THE THE	TLC7528I .		. −25°C to 85°C
	TLC7528E .		. −40°C to 85°C
Storage temperature range, T <sub>stq</sub>			-65°C to 150°C
Case temperature for 10 seconds, T <sub>C</sub> : FN			
Lead temperature 1,6 mm (1/16 inch) from			

WWW.100 † Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# recommended operating conditions

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	M. 221.100 CON!	V <sub>DD</sub> = 4.75 V to 5.25		5.25 V	V <sub>DD</sub> = 1	14.5 V to	15.5 V	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Reference voltage, V <sub>refA</sub> or V <sub>refB</sub>	MAM. OON.CO	TW	±10	MA	1003	±10	TIN	V
High-level input voltage, VIH	COM COM	2.4		WW	13.5	$\sqrt{CO_2}$		V
Low-level input voltage, V <sub>IL</sub>	W. 100 F. CO.	VII		0.8	N. Inc	-7 C.C	1.5	V
CS setup time, t <sub>Su(CS)</sub>	1007.0	50		M	50	01.	OM	ns
CS hold time, th(CS)	M MAN TOOX CO	0		W	0	007.0	-1/	ns
DAC select setup time, t <sub>Su(DAC)</sub>	WWW.I OV C	50	N	11	50	· VOO	$Co_{h_2}$	ns
DAC select hold time, th(DAC)		10			10	Too	$CO_{J}$	ns
Data bus input setup time t <sub>Su(D)</sub>	TW W. 1001.	25	. 44		25	0.700.	_d0	ns
Data bus input hold time th(D)	YOU WWW 100Y	10	TW		10	-1100	N.C.	ns
Pulse duration, WR low, tw(WR)	Mr. MWW.	50	W		50	W	V.C	ns
W.100 -	TLC7628C	. 0	1.1	70	0	MAIT	70	OMr.
Operating free-air temperature, TA	TLC7628I	-25	$M$ $\cdot$ $I$ $\cdot$	85	-25	- TW.	85	°C
	TLC7628E	-40	- ( T	85	-40	MA.	85	



# TLC7528C, TLC7528E, TLC7528I **DUAL 8-BIT MULTIPLYING** DIGITAL-TO-ANALOG CONVERTERS

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# electrical characteristics over recommended operating free-air temperature range, $V_{refA} = V_{refB} = 10 \text{ V}, V_{OA} \text{ and } V_{OB} \text{ at } 0 \text{ V} \text{ (unless otherwise noted)}$

	OW.		TEST CONDITIONS	V	V <sub>DD</sub> = 5 V			V <sub>DD</sub> = 15 V			
PARAMETER		TEST CONDITIONS	MIN	MIN TYPT MA		MIN	TYP†	MAX	UNIT		
ΪΗ	High-level input current	11 100 T	$V_I = V_{DD}$	W.10	U	10	1		10	μΑ	
l <u>l</u> L	Low-level input current	100	V <sub>I</sub> = 0	5	12	-10	5	12	-10	μΑ	
y.C	Reference input impeda REFA or REFB to AGNI		V.COM.TW W		1007	20	M.T.	N	20	kΩ	
01.	COM.TW	OUTA	DAC data latch loaded with 000000000, V <sub>refA</sub> = ±10 V	+400		TW	±200				
likg	kg Output leakage current	OUTB	DAC data latch loaded with 000000000, V <sub>refB</sub> = ±10 V	WW	W.10	±400	OM	WT	±200	nA	
V.10	Input resistance match (REFA to REFB)	MMA	N.100Y.COM.TW	W	NW	±1%	1 CO	M.TV	±1%		
- 11	DC supply sensitivity, Δο	gain/∆V <sub>DD</sub>	$\Delta V_{DD} = \pm 10\%$			0.04	(	MI	0.02	%/%	
I <sub>DD</sub>	Supply current (quiescent)		All digital inputs at V <sub>IH</sub> min or V <sub>IL</sub> max	2		7 .C	OM.	2	mA		
I <sub>DD</sub>	Supply current (standby	)	All digital inputs at 0 V or V <sub>DD</sub>		7	0.5	JU - 1	COM	0.5	mA	
M.	1100Y.CO. 11.T	DB0-DB7	M. 1001.		111	10	100,1		10	pF	
Ci	Input capacitance	WR, CS, DACA/DACB	WWW.100Y.COM.TY	1	W	15	100	I CC	15	pF	
	WW.100X.COM		DAC data latches loaded with 000000000			50	N.100	ny.C	50	TW	
Co	Output capacitance (OUTA, OUTB)		DAC data latches loaded with 11111111	WT		120 120		120	pF		

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<sup>&</sup>lt;sup>†</sup> All typical values are at  $T_A = 25$ °C. WWW.100Y.CO.

# TLC7528C, TLC7528E, TLC7528I DUAL 8-BIT MULTIPLYING DIGITAL-TO-ANALOG CONVERTERS

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# operating characteristics over recommended operating free-air temperature range, $V_{refA} = V_{refB} = 10 \text{ V}$ , $V_{OA}$ and $V_{OB}$ at 0 V (unless otherwise noted)

PARAMETER		TEST SOURITIONS	V <sub>DD</sub> = 5 V			V <sub>E</sub>			
PARAMI	PARAMETER TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Linearity error	W 1003	CONTIN	W.10	0 -	±1/2	. 1		±1/2	LSB
Settling time (to 1/2 LS	SB)	See Note 1	- 1	001.	100	In		100	ns
Gain error	MMM	See Note 2	M 41.	A OOM	2.5	WT		2.5	LSB
A C for a dth navyah	REFA to OUTA	CHI NEW 2	TWW.	70	-65	TV		-65	40
AC feedthrough REFB to OUTE		See Note 3	100 -		-65	M.r.	<b>«</b> 1	-65	dB
Temperature coefficie	nt of gain	See Note 4	Ma.	N 10	0.007	$M^{T}$	N.A.	0.0035	%FSR/°C
Propagation delay (fro 90% of final analog ou		See Note 5	WW	W.1	80	OM.	, W	80	ns
Channel-to-channel REFA to OUTB		See Note 6	44.	77	700 r.	77		40	
isolation	REFB to OUTA	See Note 7	W	77	1007	,0-01	77		dB
Digital-to-analog glitch	n impulse area	Measured for code transition from 00000000 to 111111111, TA = 25°C		160	N.100	V.Co.	440	N	nV∙s
Digital crosstalk	TW	Measured for code transition from 00000000 to 111111111, T <sub>A</sub> = 25°C		30	WW.1	ooy.C	60	TW	nV∙s
Harmonic distortion	1.1	$V_i = 6 \text{ V},  f = 1 \text{ kHz},  T_A = 25^{\circ}\text{C}$	N	-85	IWW	OV	-85	TW	dB

NOTES: 1. OUTA, OUTB load =  $100 \Omega$ ,  $C_{ext} = 13 pF$ ;  $\overline{WR}$  and  $\overline{CS}$  at 0 V; DB0–DB7 at 0 V to V<sub>DD</sub> or V<sub>DD</sub> to 0 V.

- 2. Gain error is measured using an internal feedback resistor. Nominal full scale range (FSR) = V<sub>ref</sub> 1 LSB.
- 3.  $V_{ref} = 20 \text{ V}$  peak-to-peak, 100-kHz sine wave; DAC data latches loaded with 00000000.
- 4. Temperature coefficient of gain measured from 0°C to 25°C or from 25°C to 70°C.
- 5.  $V_{refA} = V_{refB} = 10 \text{ V}$ ; OUTA/OUTB load = 100  $\Omega$ ,  $C_{ext} = 13 \text{ pF}$ ;  $\overline{WR}$  and  $\overline{CS}$  at 0 V; DB0–DB7 at 0 V to  $V_{DD}$  or  $V_{DD}$  to 0 V.
- 6. Both DAC latches loaded with 111111111; V<sub>refA</sub> = 20 V peak-to-peak, 100-kHz sine wave; V<sub>refB</sub> = 0; T<sub>A</sub> = 25°C.
- 7. Both DAC latches loaded with 111111111; V<sub>refB</sub> = 20 V peak-to-peak, 100-kHz sine wave; V<sub>refA</sub> = 0; T<sub>A</sub> = 25°C.

## PRINCIPLES OF OPERATION

These devices contain two identical, 8-bit-multiplying D/A converters, DACA and DACB. Each DAC consists of an inverted R-2R ladder, analog switches, and input data latches. Binary-weighted currents are switched between DAC output and AGND, thus maintaining a constant current in each ladder leg independent of the switch state. Most applications require only the addition of an external operational amplifier and voltage reference. A simplified D/A circuit for DACA with all digital inputs low is shown in Figure 1.

Figure 2 shows the DACA equivalent circuit. A similar equivalent circuit can be drawn for DACB. Both DACs share the analog ground terminal 1 (AGND). With all digital inputs high, the entire reference current flows to OUTA. A small leakage current ( $I_{lkg}$ ) flows across internal junctions, and as with most semiconductor devices, doubles every 10°C.  $C_0$  is due to the parallel combination of the NMOS switches and has a value that depends on the number of switches connected to the output. The range of  $C_0$  is 50 pF to 120 pF maximum. The equivalent output resistance ( $I_0$ ) varies with the input code from 0.8R to 3R where R is the nominal value of the ladder resistor in the R-2R network.

These devices interface to a microprocessor through the data bus,  $\overline{CS}$ ,  $\overline{WR}$ , and  $\overline{DACA}/DACB$  control signals. When  $\overline{CS}$  and  $\overline{WR}$  are both low, the TLC7528 analog output, specified by the  $\overline{DACA}/DACB$  control line, responds to the activity on the DB0–DB7 data bus inputs. In this mode, the input latches are transparent and input data directly affects the analog output. When either the  $\overline{CS}$  signal or  $\overline{WR}$  signal goes high, the data on the DB0–DB7 inputs is latched until the  $\overline{CS}$  and  $\overline{WR}$  signals go low again. When  $\overline{CS}$  is high, the data inputs are disabled regardless of the state of the  $\overline{WR}$  signal.



#### PRINCIPLES OF OPERATION

The digital inputs of these devices provide TTL compatibility when operated from a supply voltage of 5 V. These devices can operate with any supply voltage in the range from 5 V to 15 V; however, input logic levels are not TTL compatible above 5 V.

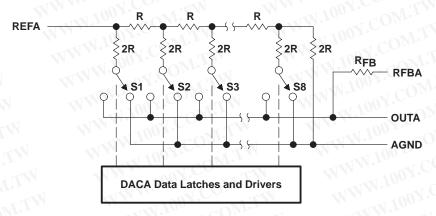
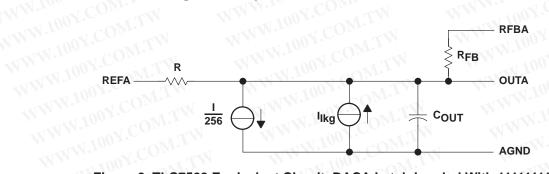


Figure 1. Simplified Functional Circuit for DACA



WWW.100Y.COM.TW Figure 2. TLC7528 Equivalent Circuit, DACA Latch Loaded With 11111111

#### **MODE SELECTION TABLE**

MODE SELECTION TABLE						
DACA/DACB	CS	WR	DACA	DACB		
- VL	L	J.L	Write	Hold		
Н	L	Lan	Hold	Write		
X	H 1	X	Hold	Hold		
X	Х	Н	Hold	Hold		

L = low level, H = high level, X = don't care

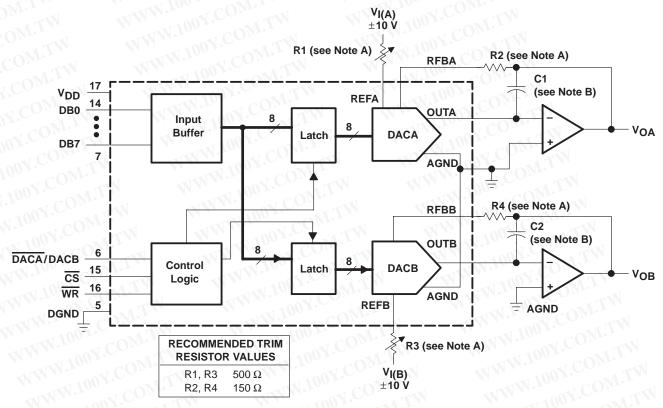
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#### **APPLICATION INFORMATION**

These devices are capable of performing 2-quadrant or full 4-quadrant multiplication. Circuit configurations for 2-quadrant and 4-quadrant multiplication are shown in Figures 3 and 4. Tables 1 and 2 summarize input coding for unipolar and bipolar operation.

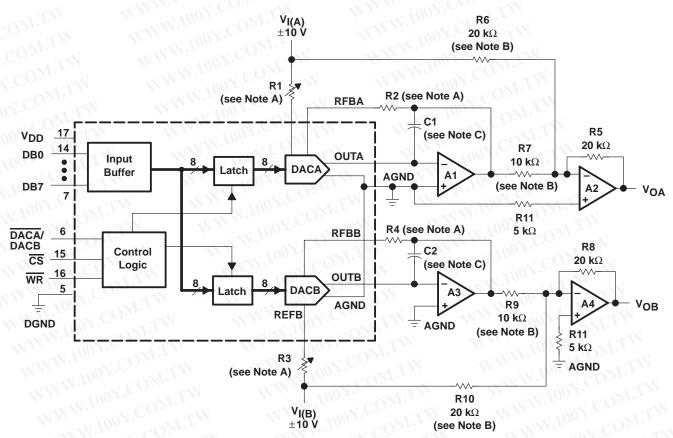


- NOTES: A. R1, R2, R3, and R4 are used only if gain adjustment is required. See table for recommended values. Make gain adjustment with digital input of 255.
  - B. C1 and C2 phase compensation capacitors (10 pF to 15 pF) are required when using high-speed amplifiers to prevent ringing or oscillation.

Figure 3. Unipolar Operation (2-Quadrant Multiplication)



# **APPLICATION INFORMATION**



- NOTES: A. R1, R2, R3, and R4 are used only if gain adjustment is required. See table in Figure 3 for recommended values. Adjust R1 for VOA = 0 V with code 10000000 in DACA latch. Adjust R3 for VOB = 0 V with 10000000 in DACB latch.
  - B. Matching and tracking are essential for resistor pairs R6, R7, R9, and R10.
  - C. C1 and C2 phase compensation capacitors (10 pF to 15 pF) may be required if A1 and A3 are high-speed amplifiers.

Figure 4. Bipolar Operation (4-Quadrant Operation)

Table 1. Unipolar Binary Code

DAC LATCH CONTENTS	ANALOG OUTPUT
MSB LSB <sup>†</sup>	ON.CO. TW
11111111	-V <sub>I</sub> (255/256)
1000001	-V <sub>I</sub> (129/256)
1000000	$-V_{\rm I}$ (128/256) = $-V_{\rm i}/2$
01111111	-V <sub>I</sub> (127/256)
0000001	−V <sub>I</sub> (1/256)
0000000	$-V_{I}(0/256)=0$

†1 LSB =  $(2^{-8})V_I$ 

Table 2. Bipolar (Offset Binary) Code

- / 1 / 1 / 2 / 2 / 3 / 3 / 3 / 3 / 3 / 3 / 3 / 3	
DAC LATCH CONTENTS  MSB LSB <sup>‡</sup>	ANALOG OUTPUT
1111111	V <sub>I</sub> (127/128)
1000001	V <sub>I</sub> (1/128)
1000000	0 V
01111111	−V <sub>I</sub> (1/128)
0000001	-V <sub>I</sub> (127/128)
0000000	-V <sub>I</sub> (128/128)

 $^{\ddagger}1 LSB = (2^{-7})V_{I}$ 

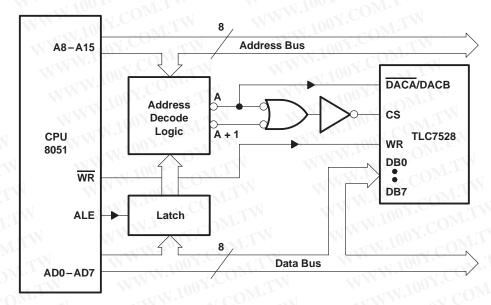


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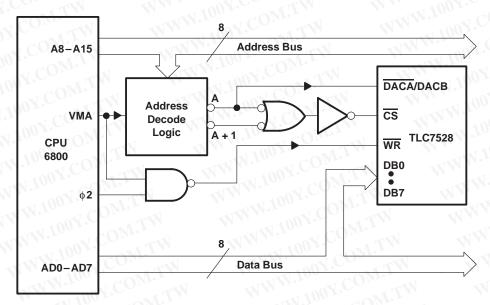
#### **APPLICATION INFORMATION**

# microprocessor interface information



NOTE A: A = decoded address for TLC7528 DACA A + 1 = decoded address for TLC7528 DACB

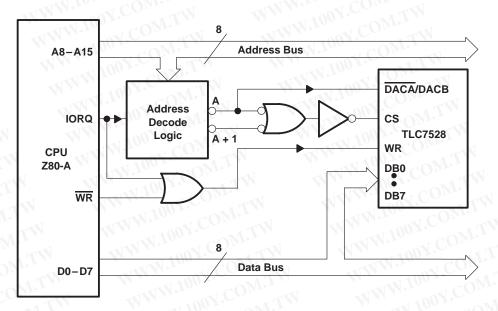
Figure 5. TLC7528 - Intel 8051 Interface



NOTE A: A = decoded address for TLC7528 DACA
A + 1 = decoded address for TLC7528 DACB

Figure 6. TLC7528 - 6800 Interface

#### **APPLICATION INFORMATION**



NOTE A: A = decoded address for TLC7528 DACA
A + 1 = decoded address for TLC7528 DACB

Figure 7. TLC7528 To Z-80A Interface

## programmable window detector

The programmable window comparator shown in Figure 8 determines if voltage applied to the DAC feedback resistors are within the limits programmed into the data latches of these devices. Input signal range depends on the reference and polarity, that is, the test input range is 0 to  $-V_{ref}$ . The DACA and DACB data latches are programmed with the upper and lower test limits. A signal within the programmed limits drives the output high.



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#### **APPLICATION INFORMATION**

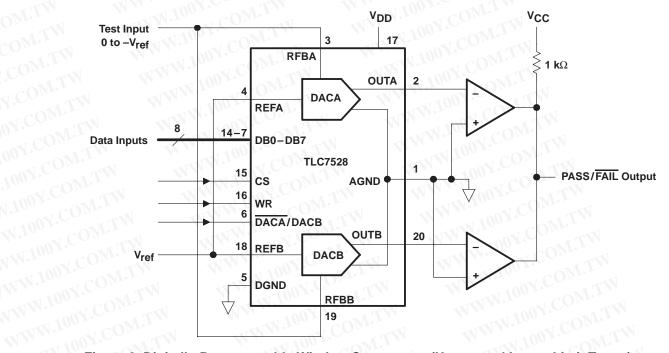


Figure 8. Digitally-Programmable Window Comparator (Upper- and Lower-Limit Tester)

## digitally controlled signal attenuator

Figure 9 shows a TLC7528 configured as a two-channel programmable attenuator. Applications include stereo audio and telephone signal level control. Table 3 shows input codes vs attenuation for a 0 to 15.5 dB range.

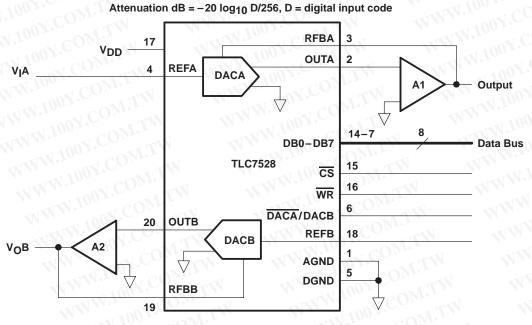


Figure 9. Digitally Controlled Dual Telephone Attenuator



#### APPLICATION INFORMATION

Table 3. Attenuation vs DACA, DACB Code

ATTN (dB)	DAC INPUT CODE	CODE IN DECIMAL	ATTN (dB)	DAC INPUT CODE	CODE IN
0	11111111	255	8.0	01100110	102
0.5	11110010	242	8.5	01100000	96
1.0	11100100	228	9.0	01011011	91
1.5	11010111	215	9.5	01010110	86
2.0	11001011	203	10.0	01010001	81
2.5	11000000	192	10.5	01001100	76
3.0	10110101	181	11.0	01001000	72
3.5	10101011	171	11.5	01000100	68
4.0	10100010	162	12.0	01000000	64
4.5	10011000	152	12.5	00111101	61
5.0	10011111	144	13.0	00111001	57
5.5	10001000	136	13.5	00110110	54
6.0	10000000	128	14.0	00110011	51
6.5	01111001	121	14.5	00110000	48
7.0	01110010	114	15.0	00101110	46
7.5	01101100	108	15.5	00101011	43

## programmable state-variable filter

This programmable state-variable or universal filter configuration provides low-pass, high-pass, and bandpass outputs, and is suitable for applications requiring microprocessor control of filter parameters.

As shown in Figure 10, DACA1 and DACB1 control the gain and Q of the filter while DACA2 and DACB2 control the cutoff frequency. Both halves of the DACA2 and DACB2 must track accurately in order for the cutoff-frequency equation to be true. With the TLC7528, this is easy to achieve.

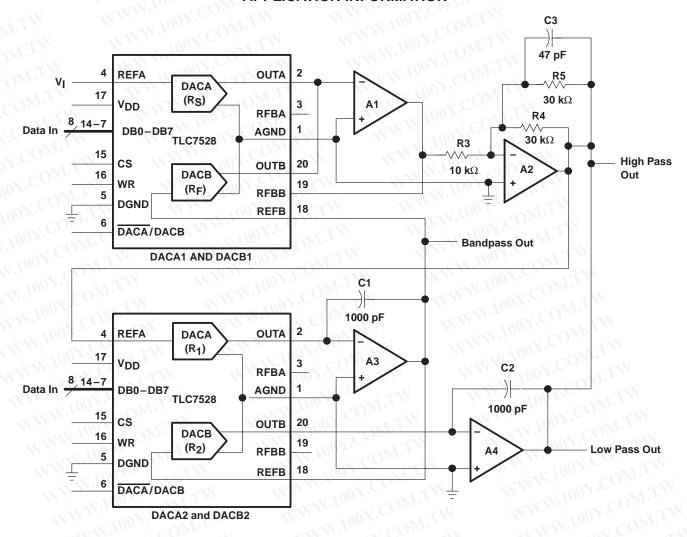
$$f_{C} = \frac{1}{2\pi R1C1}$$

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The programmable range for the cutoff or center frequency is 0 to 15 kHz with a Q ranging from 0.3 to 4.5. This defines the limits of the component values.



#### APPLICATION INFORMATION



**Circuit Equations:** 

$$C_1 = C_2, R_1 = R_2, R_4 = R_5$$

$$Q = \frac{R_3}{R_4} \cdot \frac{R_F}{R_{fb(DACB1)}}$$

Where:

 ${\sf R}_{\sf fb}$  is the internal resistor connected between OUTB and RFBB

$$G = -\frac{R_F}{R_S}$$

NOTES: A. Op-amps A1, A2, A3, and A4 are TL287.

B. CS compensates for the op-amp gain-bandwidth limitations.

C. DAC equivalent resistance equals  $\frac{256 \times (\text{DAC ladder resistance})}{\text{DAC digital code}}$ 

Figure 10. Digitally Controlled State-Variable Filter





#### **APPLICATION INFORMATION**

#### voltage-mode operation

It is possible to operate the current multiplying D/A converter of these devices in a voltage mode. In the voltage mode, a fixed voltage is placed on the current output terminal. The analog output voltage is then available at the reference voltage terminal. Figure 11 is an example of a current multiplying D/A, that operates in the voltage mode.

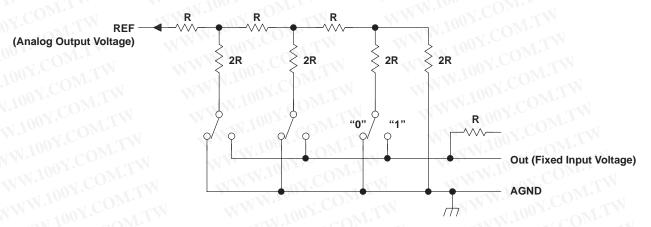


Figure 11. Voltage-Mode Operation

The following equation shows the relationship between the fixed input voltage and the analog output voltage:

$$V_O = V_I (D/256)$$

Where:

V<sub>O</sub> = analog output voltage

V<sub>I</sub> = fixed input voltage (must not be forced below 0 V.)

D = digital input code converted to decimal

In voltage-mode operation, these devices meet the following specification:

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Linearity error at REFA or REFB	$V_{DD} = 5 \text{ V}$ , OUTA or OUTB at 2.5 V, $T_A = 25^{\circ}\text{C}$		1	LSB
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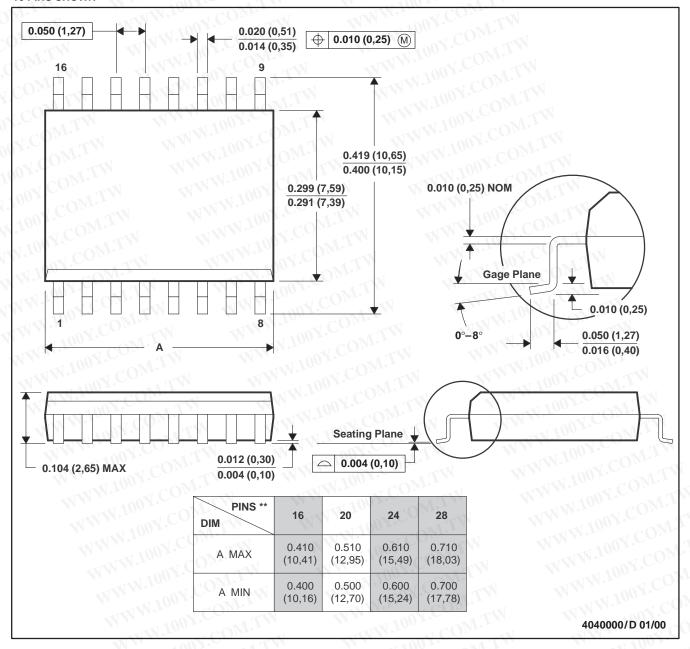


#### **MECHANICAL DATA**

# DW (R-PDSO-G\*\*)

## 16 PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013

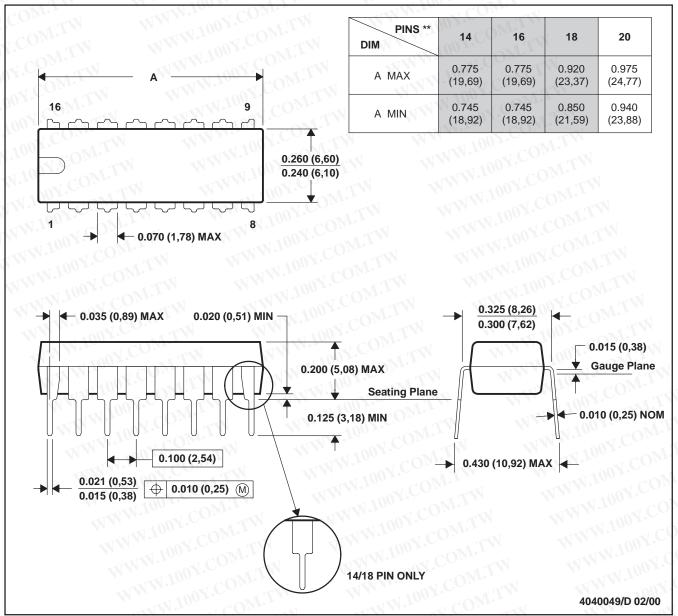


#### **MECHANICAL DATA**

#### N (R-PDIP-T\*\*)

#### **16 PINS SHOWN**

#### PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 (20-pin package is shorter than MS-001).



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